

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

APT20M18LVR

FEATURES

- Drain Current –I_D= 100A@ T_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V_{DSS}=200V(Min)
- Static Drain-Source On-Resistance : R_{DS(on)} =0.018 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

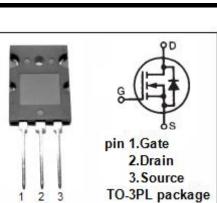
• Designed for use in switch mode power supplies and general purpose applications.

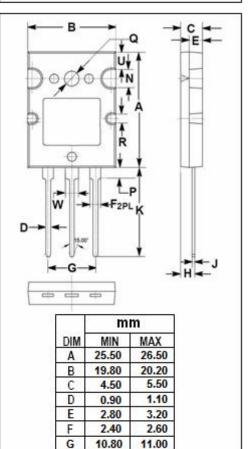
SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	200	V				
V _{GS}	Gate-Source Voltage-Continuous	±30	V				
ID	Drain Current-Continuous	100	A				
I _{DM}	Drain Current-Single Pluse	400	A				
PD	Total Dissipation @Tc=25℃	625	W				
TJ	Max. Operating Junction Temperature -55~150		°C				
T _{stg}	Storage Temperature -55~150		°C				

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.20	°C/W





3.10

0.50

3.90

2.40

3.10

1.90

3.90

2.90

20.00

Н

J

Κ

Ν

Ρ

Q

R

U W 3.30

0.70

21.00

4.50

2.60

3.50

2.60

4.10

3.25



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	200		V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 2.5mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =50A		0.018	Ω
lgss	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 200V; V _{GS} = 0 V _{DS} = 160V; V _{GS} = 0@T _C =125°C		25 250	μA
V _{SD}	Forward On-Voltage	I _S =-49A; V _{GS} = 0		1.3	V

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